

Advanced settings

FLUKA Advanced Course

Preliminary considerations:

FLUKA is NOT a toolkit!!!!

The development team strives to provide the best possible physics it can develop, rather than a choice among several possible alternative models

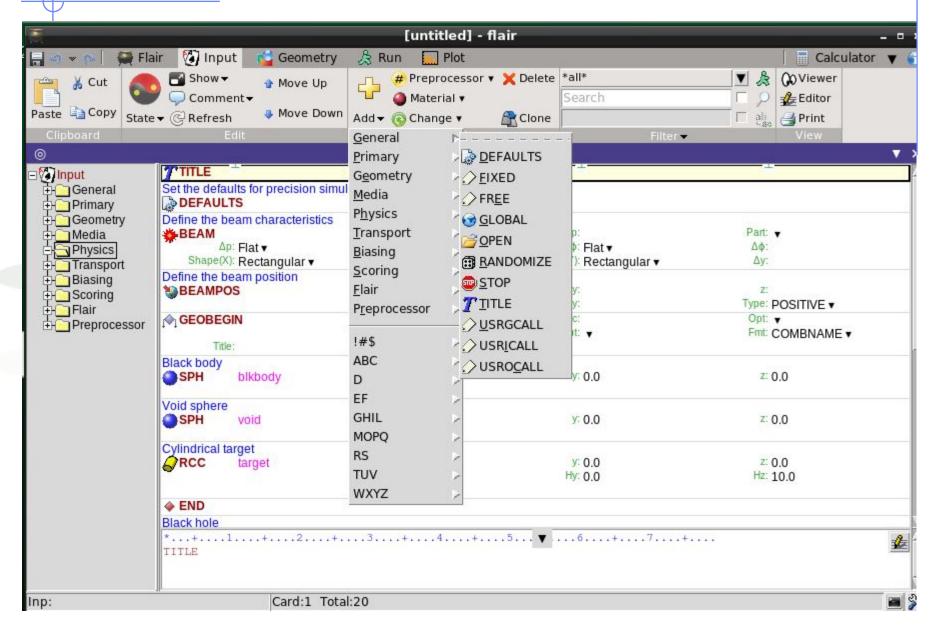
Hence there are not many "physics" knobs to play with (ideally there should be no one)

The user has mostly to set thresholds/cuts, and switch on/off a few processes which for various reasons are not on/off by default

The DEFAULT card

- The DEFAULT card is there to help you: choose the one nearest to your problem
- The "default" **NEW-DEFA** is the "crudest" one: often it will not be suited for your problem, check with care, don't use it blindly..
- The "default" DEFAULT proposed by FLAIR is PRECISIO while for the code is NEW-DEFA
- Check all settings: look in the output, at least the 1st time you setup a new problem!
- Always set production and transport thresholds.

Managing DEFAULTS with FLAIR



Summary: ionization and tracking

- Charged particles tracking: according to *Molière** multiple Coulomb scattering (MCS), i.e., it computes deflection, displacement and step shortening as a cumulative effect of all Coulomb scatterings along a charged particle step.
- Ionization energy losses: divided in
 - Discrete, above a pre-set threshold (" δ -ray" emission)
 - Continuous, below this threshold: energy is deposited uniformly along a step, according to the average and fluctuation of the specific energy loss.
- Tracking termination: particle below the transport threshold (or interaction, decay, escape...)

^{*} Single scattering available on option

Reminder: discrete δ -ray events

Above a pre-set threshold, secondary electron production is modeled as δ ray production (free electrons)

- Spin 0 or $1/2 \delta$ -ray production (charged hadrons, muons)
- Bhabha scattering (e⁺)
- Møller scattering (e⁻)

The threshold refers to the kinetic energy of the emitted δ ray

- ✓ For Electrons: set by EMFCUT with sdum= PROD-CUT*
- For charged hadrons/muons:

 Both cards set (production) thresholds

 by material
 - > It can be complemented by (consistent) transport thresholds (EMFCUT with no sdum) if more granularity is required
 - > Tabulations are built at initialization time based on production thresholds: important for precision
 - > If very different settings are needed for the same material in different regions -> may be wise to define instead different materials with different production thresholds

^{*} Remember : what(3) is related to multiple scattering. MUST be set, if the field is empty $\rightarrow 0$ set= 0 below \approx 10 keV , = 1 above

Summary: particle transport thresholds

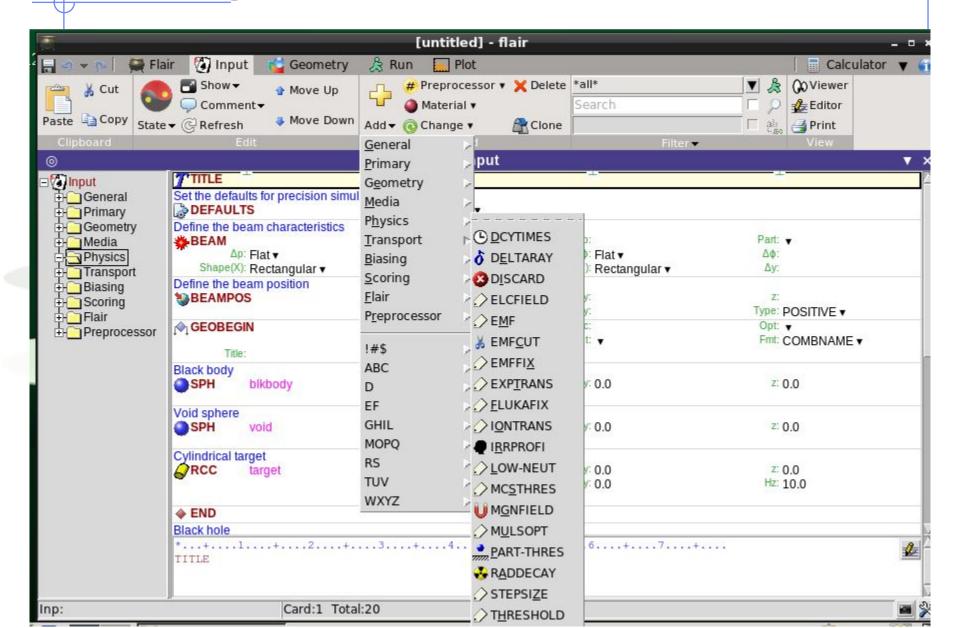
- Hadron and muon transport thresholds are set with the PART-THRes
 card for the whole simulated setup
- The total momentum/energy cut-off's of heavy ions are scaled from that of a 4-He ion (4-HELIUM) according to the mass ratio
- The total momentum/energy cut-offs for light ions (4-He, 3-He, 3-H, 2-H) can be defined by PART-THRes. If this is not done, they are scaled from that of a proton according to the mass ratio
- Electron and photon transport thresholds are set with the EMFCUT card, no sdum, by region, production threshold again with the EMFCUT card, sdum=PROD-CUT, by material
- Neutron thresholds through PART-THR or LOW-BIAS

What happens after?

- Electrons and photons are stopped, their energy is deposited "on spot"
- Charged hadrons/muons are ranged out to rest with approximate tracking
 if the threshold is lower than 100 MeV, and particles are decayed, or
 annihilated on a nucleus, or captured if applicable. For thresholds higher
 than 100 MeV hadrons are dumped on spot without further treatment.
- Low-E neutrons: when stopped, the kinetic energy is deposited on spot: not realistic for calculation of energy deposition and activation → track them down to thermal unless you don't care!

7

Setting Thresholds with FLAIR



How to set thresholds?

It depends on

- the "granularity" of the geometry
- the granularity of the scoring mesh
- the "interest" in a given region.
- Electron equilibrium at boundaries
- CPU time...

In practice: compare the dimensions of the "problem" with the range of particles at the threshold energy. Energy/range tables are very useful (see for instance http://physics.nist.gov)

Warning: to reproduce correctly electronic equilibrium, neighboring regions should have the same electron energy (NOT range in cm) threshold. To be kept in mind for sampling calorimeters

Warning: photons travel much more than electrons.

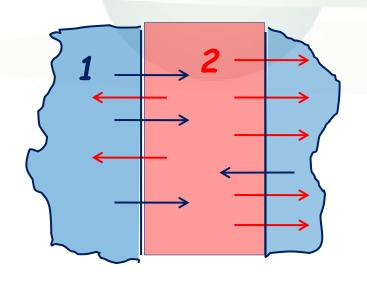
Warning: Threshold for antineutrons and neutral kaons should always be kept low.

Neutrons: see later

Electronic equilibrium, considerations:

The average stopping power, dE/dx, depends on the material only (weakly) for I (average ionization potential), and for $\langle Z/A \rangle$. The I dependence concerns only with distant collisions and it is not a source of disequilibrium at interfaces.

However electrons (δ -rays) emitted in close collisions can travel further. At an interface between 1 and 2 this effect can reduce (increase) the stopping power experienced in 2 if $\langle Z/A \rangle_1$ is smaller (larger) than $\langle Z/A \rangle_2$



- For a correct measurement of stopping power in a given material, surrounding materials should be chosen with care
- For a correct evaluation of energy deposition in a given multilayer setup, thresholds must be accurately set in the interested regions and in the surrounding ones

Electronic equilibrium, considerations II:

- For a precise measurement of dE/dx in medium 2 it is essential that $\langle Z/A \rangle_1 = \langle Z/A \rangle_2$ before and after the sensitive volume, so that electronic equilibrium is achieved
- The thickness of the layer of "equivalent" material should be comparable or larger of the range of the most energetic secondary electrons \rightarrow impossible for incident electrons and relativistic particles
- Density differences do not matter, and they are automatically corrected for when results are expressed in deposited energy per unit mass (=dose)
- The special case when medium 1 is vacuum produces the buildup region, which extends up to the range of the most energetic electrons
- Thresholds should be set according to these considerations, so that
 - > They are equal on both sides of the interface
 - They are *low enough* to assure electronic equilibrium except for a negligible region

Electronic equilibrium, considerations III:

When *photons* are involved or the energy of the incident particles is large enough to make bremsstrahlung significant:

- For a precise measurement of **dose** in medium 2 it is essential that $\langle Z/A \rangle_1 = \langle Z/A \rangle_2$ before and after the sensitive volume, so that electronic equilibrium is achieved for charged particles
- It is also essential that $\langle Z^2/A \rangle_1 = \langle Z^2/A \rangle_2$ before and after the sensitive volume for pair production and bremsstrahlung
- ... and also $\langle Z^n/A \rangle_1 = \langle Z^n/A \rangle_2$, $n \sim 5$, before and after the sensitive volume for photoelectric
- The **thickness** of the layer of "equivalent" material should be comparable or larger of the **range of the most energetic secondary electrons** produced by the photons \rightarrow often impossible to achieve
- Threshold should be equal, and low enough to assure minimal disequilibrium

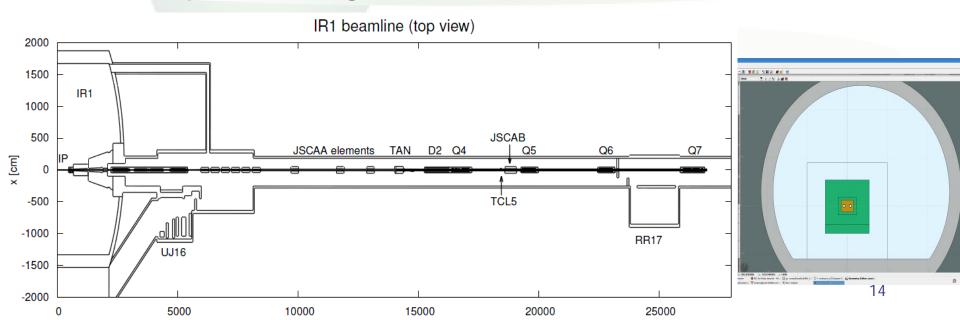
Electronic equilibrium, considerations IV:

When *neutrons* are involved or the energy of the incident hadron is large enough to make nuclear reactions significant:

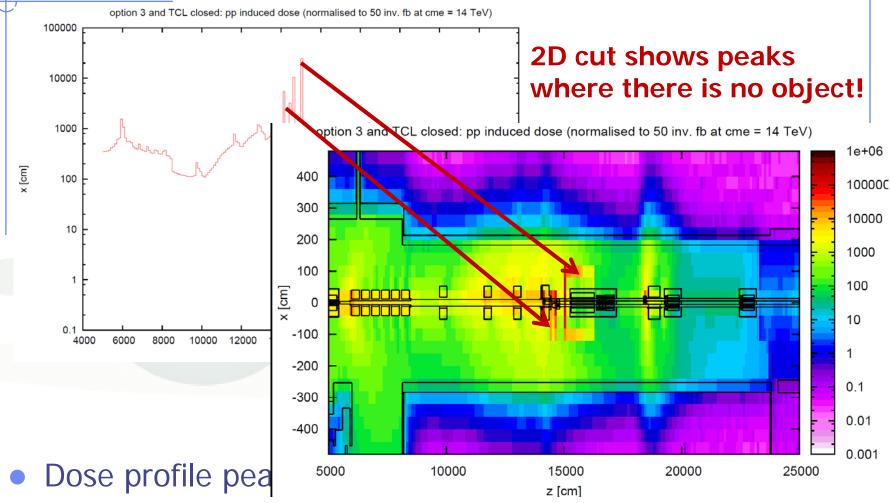
- For a precise measurement of **dose** in medium 2 it is essential that the **chemical composition** before and after the sensitive volume is the same
- When this is not possible, at least the hydrogen (fractional) content should be made the same
- The thickness of the layer of "equivalent" material should be comparable or larger of the range of the most energetic secondary charges particles (recoil protons for neutrons) produced
- Unless you are sure, track neutrons down to thermal energies!

Example 1: A huge geometry

- CERN LHC tunnel adjacent to ATLAS
- Interested in debris 200m downstream source point
- How to get 'better' statistics
 - Heavy biasing
 - High thresholds in areas not of interest
- BUT: then use of same setup to have a look on the dose profile along the beam-line



First Results look first 'possible'



 BUT: values are a factor of 10 higher than an 'over the thumb check' (fortunately) -> the reason?

Reason & Correction

High thresholds in tunnel air regions:

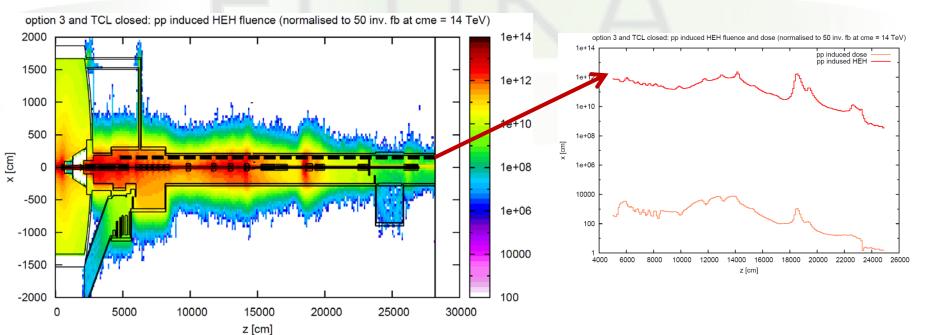
```
*...+....1....+....2....+....3....+....4....+....5....+....6....+....7..

EMFCUT -0.050 0.0500 0.0 R208

EMFCUT -0.050 0.0500 0.0 R204

EMFCUT -0.050 0.0500 0.0 R206
```

- Lead to unnatural energy deposition on the spot
- Lowering the thresholds solves the issue



Example 2:

Water- Lead-Aluminum layers

Dose

50 microns each

$$25\mu \ Pb = 2.8 \ 10^{-2} \ g/cm^2$$

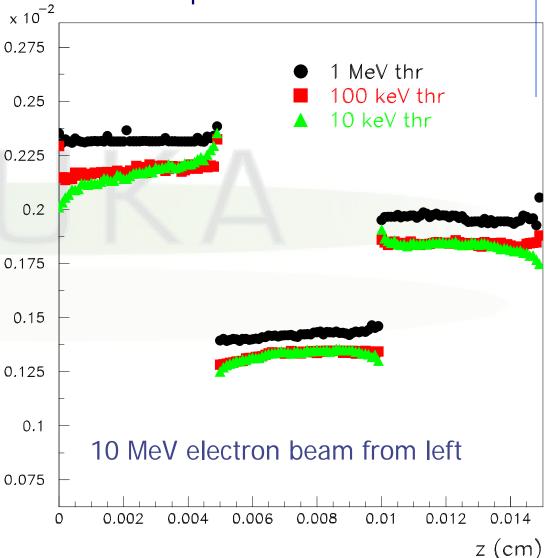
→ 100 keV

$$1\mu \text{ Pb} = 1.1 \ 10^{-3} \text{g/cm}^2$$

→ 12keV

- High threshold gives overestimated results because electrons cannot escape
- Medium threshold is reasonable for average value in layer
- Low threshold needed if scoring grid is fine





Neutron thresholds

Neutrons can interact at any energy, down to thermal, with exothermic or endothermic reactions. The simple assumption of kinetic energy deposition used below threshold is a gross approximation, therefore:

- For all problems involving energy deposition, residual nuclei production, and of course neutron propagation: leave the default (last thermal group, 1.10⁻⁵eV)
- A threshold can be set (PART-THR if above 20 MeV, PART-THR or LOW-BIAS below) only if the problem treated is intrinsically not sensitive to low energy particles (detectors with a threshold, neutrino beams..)

Neutron setting for full analogue runs

- non-analogue absorption: biasing technique used to increase/decrease the absorption probability in low-energy neutron transport. Used to save CPU since it minimizes bouncing of neutrons in materials with low absorption probability (or enhance survival in high absorption ones). In FLUKA, with many DEFAULTs options, non-analogue absorption is applied to all thermal groups. This is not suited for fully analogue calculations, like for instance event-by-event detector response*, or for problems with very low absorption probability
- To inhibit it, use the LOW-BIAS card with WHAT(2)=261 (last neutron group+1).
- WHAT(3) sets the level of non-analogue absorption through the value of its complement, the non-analogue survival probability: phyisical value is $1-\sigma_{abs}/\sigma_{tot}$ default value for thermal groups is 0.95 (PRECISIOn and CALORIMEter defaults excluded, see next slide)

^{*} A fully analogue event-by-event transport of neutrons below 20 MeV is anyway impossible due to the inclusive nature of the xsec databases

Differences in the pre-release version for the course the prod. version

 In the pre-release, also HADRONTHE does not have non-analogue absorption activated

Neutron setting for full analogue runs -II

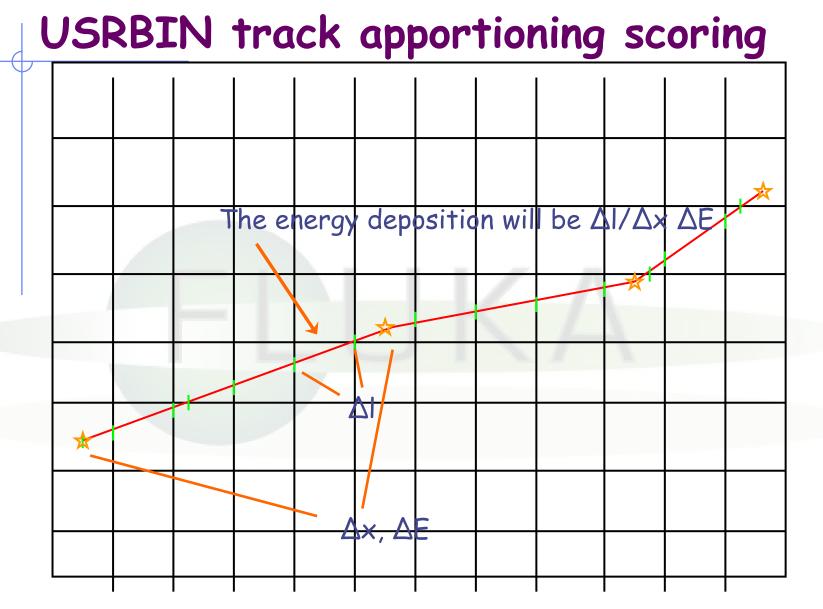
- Pointwise neutron transport is available for ¹H (above 10 eV if bound H requested, down to 10⁻⁵ eV otherwise) and ⁶Li
- Detailed correlated reaction products are available for ^{1}H , ^{6}Li , ^{10}B (only for the reaction $^{10}B(n,\alpha)^{7}Li)$, and the $^{14}N(n,p)$ reaction. All reaction products are then transported explicitly according to transport setting (PHYSICS).
- Recoil proton production is ON by default for H and $^{14}N(n,p)$
- while for the others and for pointwise treatment it depends on the DEFAULT set chosen
- Both are important for precision studies, detector response (exp. scintillators), borated materials...
- To require pointwise neutron transport and reaction products (where available), use the LOW-NEUT card with WHAT(6)=1 (see next slide)

Differences in the pre-release version for the course the prod. version

- In the pre-release, full pointwise is now available for ²H, ³He and ⁴He
- same for correlated products

Some warnings about scoring:

- Every charged particle step Δx has its length constrained by:
 - Maximum fractional energy loss (see FLUKAFIX)
 - Maximum step size for that region (see STEPSIZE)
 - MCS (or other) physical constraints
 - Distance to next interaction (nuclear, δ ray etc)
- The average energy loss is computed as a careful integration over the dE/dx vs energy curve and then it is fluctuated \rightarrow a final ΔE is computed and used for scoring \rightarrow resulting in a scored average effective $\Delta E/\Delta x$ uniform along that step
- The particle energy utilized for track-length estimators (USRTRACK) is the average one along the step (E_0 - $\Delta E/2$)
- Artifacts can show up if the scoring meshes are inconsistent with the tracking parameters:



The energy deposited in a single physical step is EQUALLY distributed in the crossed cells (proportionally to dx)

Single Scattering

- In very thin layers, wires, or gases, the Molière theory of multiple scattering does not apply.
- In FLUKA, it is possible to replace the standard multiple scattering algorithm by single scattering in defined materials (option MULSOPT).
- CPU demanding, but affordable and very accurate at low electron energies, can be tuned x material!
- Can be activated separately for electrons and hadrons and muons
- Can be activated partially, i.e.
 - only near boundaries,
 - near boundaries and for short steps
 - near boundaries and for short steps and for too low energies
- Can be activated globally, always replacing MCS in the selected material(s). (Setting WHAT(6) > 1000.0 with SDUM = \underline{GLOBAL} , $\underline{GLOBHAD}$ or $\underline{GLOBEMF}$).

More control on multiple scattering

Further control of the multiple scattering algorithm can be done with the MULSOPT card:

- Require optimisation of MCS: in this case the program always makes the minimum step for which the Molière theory of multiple scattering is applicable. Very CPU consuming, discouraged, better use single scattering at boundaries or for very short steps
- Set the maximum step length near boundaries
- Activate all or part of the corrections to the Molière cross section (spin-relativistic, form factors)
- All not needed in shielding problems, but sometimes important for backscattering and precision dosimetry
- Can be tuned by material.
- Special feature: possibility to suppress multiple scattering (applications: gas bremsstrahlung, proton beam interactions with residual gas, debugging)

Control of step size

dE/dx step sizes are optimized by the **DEFAULT** settings. If the user *really* needs to change them

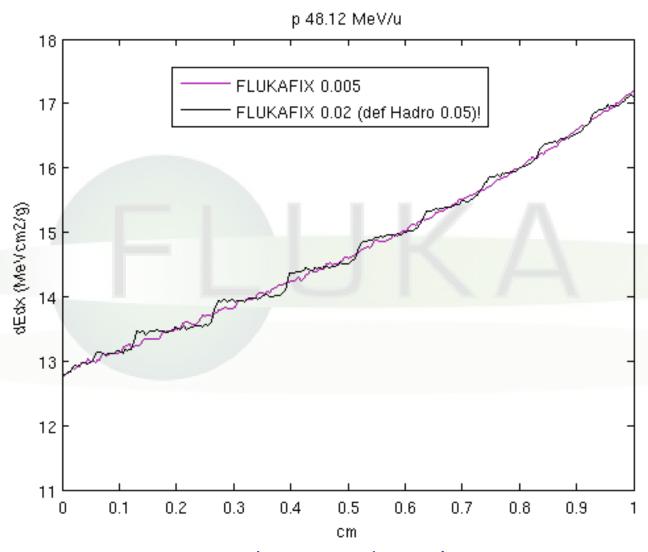
EMFFIX Mat1 DEs	step1 Mat2 DEstep2	Mat3 D	Estep3	EM
FLUKAFIX DEstep	Mat1	Mat2 S	tep	Had

DEstep should always be below 30%

• In most routine problems, a 20% fraction energy loss (== default) gives satisfactory results. *For dosimetry, 5-10% should be preferred.*

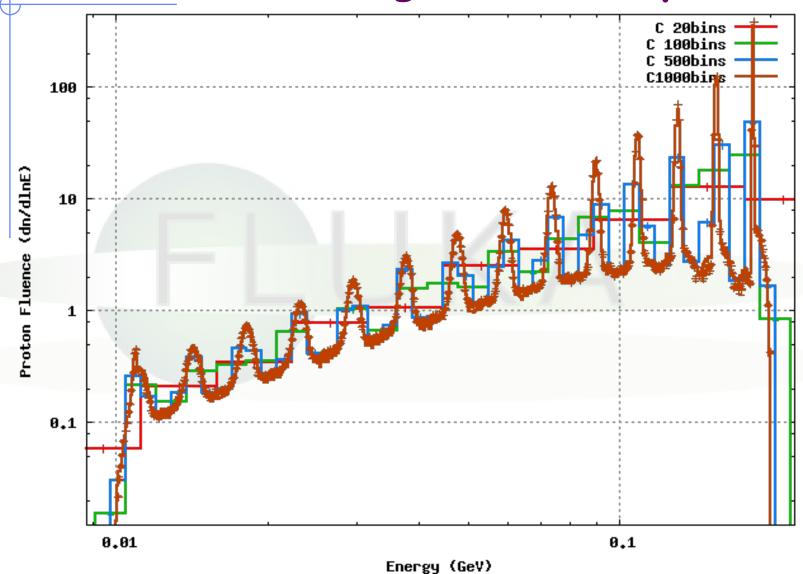
WARNING: if a magnetic field is present, it is important to set also a maximum absolute step length and possibly a precision goal for boundary crossing by means of command **STEPSIZE** (Magn. Field lecture)

USRBIN track apportioning scoring



Steps can appear in the scored results

USRTRACK scoring: 200 MeV p on C



Default settings, \approx 20% energy loss per step

More control on ionization

Ionization fluctuations are simulated or not depending on the DEFAULTS used. Can be controlled by **IONFLUCT**. Leave on unless for testing

For gaseous detectors, FLUKA can provide the list of primary ionization events, their location and energy according to (a very simplified) model. In order to activate it a few user-provided parameters are required

IONFLUCT 1stIon np_mip model Mat1 Mat2 MatStep PRIM-ION

- \triangleright 1stion: effective 1st ionization potential of the gas (eV)
- np_mip: number of primary ionizations per cm for a minimum ionizing particle
- > model: 1-4 (there are 4, all very approximate, models available)
- > From material Mat1 to material Mat2, in steps of MatStep

The primary ionization events for each (charged) particle step will be recorded in common (ALLDLT) (look at it for details!)

Reminder: The FLUKA hadronic Models

Hadron-nucleus: PEANUT

Elastic, exchange

Phase shifts data, eikonal

P<3-5GeV/c

Resonance

prod

and decay

hadron

nadron

low E п,*К*

Special

High Energy

DPM

hadronizatio

Sophisticated

G-Intranuclear Cascade

Gradual onset of

Glauber-Gribov multiple

interactions

Preequilibrium

Coalescence

Evaporation/Fission/Fermi break-up γ deexcitation

Hadronic interactions

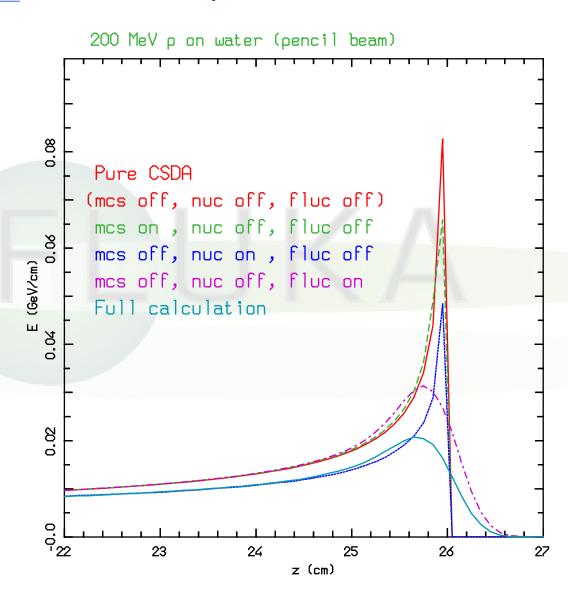
- For activation, radiation damage, and similar studies: switch on coalescence and heavy fragment emission (PHYSICS card)
- Do not forget to enable ion transport and interactions (IONTRANS*) and link with ldpmqmd when heavy ions are of interested
- For "precision" hadron physics at high energies, residual nuclei, or neutrino beam production: use the extended PEANUT model (PEATHRESH) [reminder: in the prod. version the default is to use the old, less refined intranuclear cascade model for projectile momenta >≈ 5 GeV/c]
- For electron accelerators, muon transport and underground physics: remember that muon and photon nuclear interactions are *OFF* by default. Switch them on with MUPHOTON and PHOTONUC, and bias them
- ONLY for understanding the relative impact of different processes, hadron elastic and/or inelastic interactions can be switched OFF with the THRESHOLD card.

^{*} No longer EVENTYPE!

Differences in the pre-release version for the course the prod. version

 In the pre-release, PEANUT is default at all energies

Bragg peaks: ideal proton case



Heavy ion transport and interactions

- The accuracy level of Heavy Ion transport can be set through the IONTRANS card:
 - WHAT(3) >= 1.0: no ion transport at all
 - WHAT(3) =-1.0 : approximated transport of ions and recoils (dE/dx only)
 - WHAT(3) =-2.0: all heavy recoils and ions are transported with energy loss and multiple scattering,
 - ◆ With nuclear interactions up to ~100 MeV/n with BME
 - With nuclear interactions also at higher energies if rQMD and DPMJET are linked
 - 3.0 =< WHAT(3) =< 6.0: heavy recoils up to |particle id| = WHAT(3) are transported with energy loss and multiple scattering, but no nuclear interactions (3=d,4=t,5=3-He,6=4-He)
- With many DEFAULTs, there is no transport at all!
- Remember to select ion transport and interactions for precision problems (i.e. precision dosimetry)
- Remember to select ion transport and interactions if coalescence and/or fragmentation are active
- Remember to select ion transport and interactions if DPA calculations are requested

Heavy ion interactions: warnings

- Interactions of very light ions: d, ³H, ³He in the prod. version are not simulated at low energies (E<100 MeV/A), where the BME model is used (see next slide)
- The same reactions are performed at higher energies through the RQMD and DPMJET interfaces, in the same way as all other ions. In particular, deuteron stripping is NOT modeled.
- → take with care if specific applications are concerned.
- Work is in progress on this subject
- Remember to build the correct fluka executable if ion interactions above the BME threshold are needed

Differences in the pre-release version for the course the prod. version

3H and 3He interactions are now simulated by BME

Summary of precision hadronic settings

Activate PEANUT at all energies

PHYSICS 1000. 1000. 1000. 1000. 1000. PEATHRESH

Activate Coalescence

PHYSICS 1. COALESCE

Activate heavy fragment evaporation

PHYSICS 3. EVAPORAT

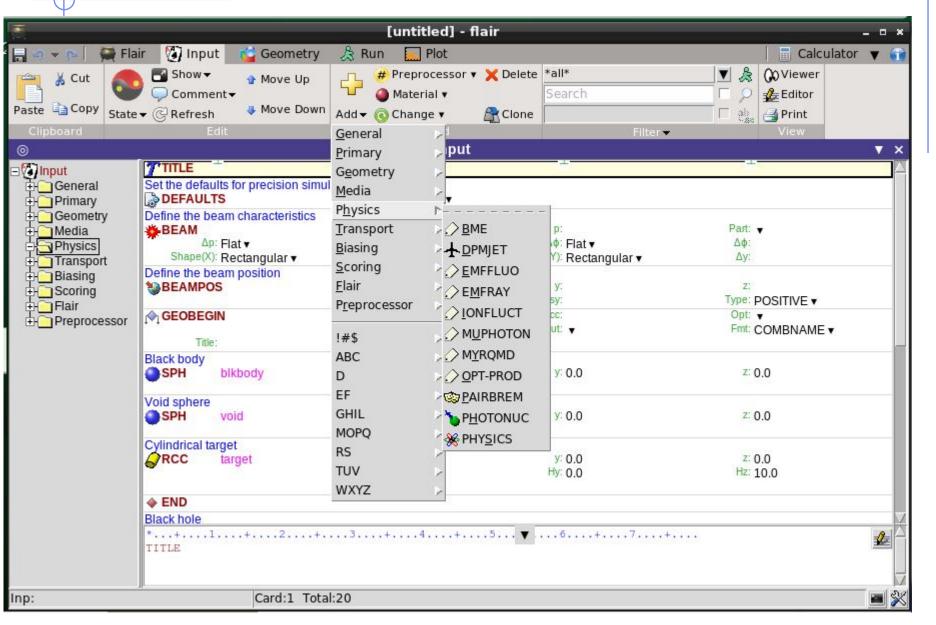
Activate ion transport and interactions

IONTRANS -2.0

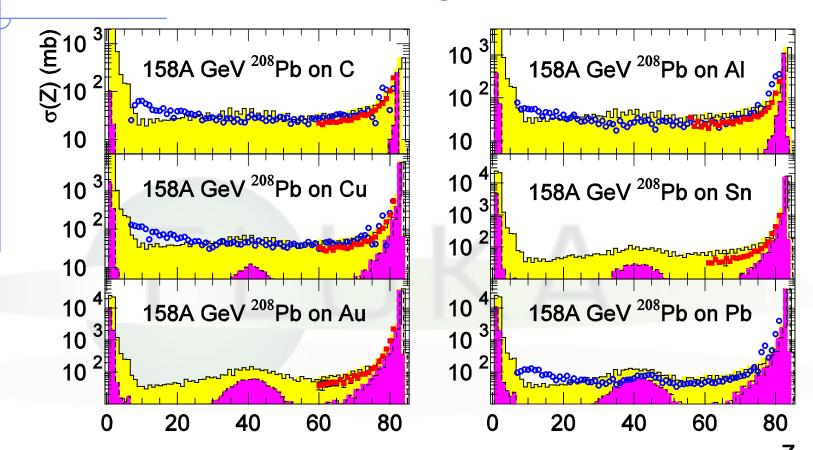
And for energetic heavy ions, activate electromagnetic dissociation

PHYSICS 2. EM-DISSO

Setting PHYSICS with FLAIR



EMD: 158 GeV/n Pb ion fragmentation

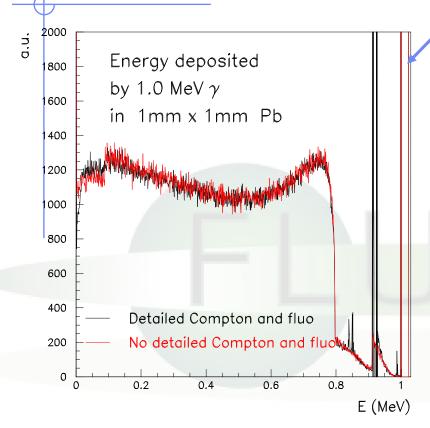


Fragment charge cross section for 158 AGeV Pb ions on various targets. Data (symbols) from NPA662, 207 (2000), NPA707, 513 (2002) (blue circles) and from C.Scheidenberger et al. PRC70, 014902 (2004), (red squares), yellow histos are FLUKA (with DPMJET-III) predictions: purple histos are the electromagnetic dissociation contribution

E-M interactions

- Cards are available to tailor the level of precision in the simulation of E-M processes. As usual, precision has a price in terms of CPU.
- Precision settings require consistent transport thresholds: it is useless to generate a fluorescence x-ray if it is immediately dumped.
- There is even the possibility to switch off (or increase the threshold) for some of the E.M. interactions through the EMFCUT card with sdums ELPO-THR, ANNH-THR, PHOT-THR, PHO2-THR. Use only for debugging purposes

Photoelectric effect



To activate/deactivate fluorescence:

EMFFLUO card, works by material

Photoelectric line

Fluorescence after photoelectric is activated only with a subset of DEFAULTs

If non-active, the energy equivalent to the x-ray is dumped at the interaction point

If active, an x-ray is emitted and tracked. (or Auger electron)

CPU time vs. precision in small granularity.

Important, for instance, in dosimetry, or whenever the granularity of the problem compares with the range of fluorescence x-rays.

Compton/Rayleigh: EMFRAY card.

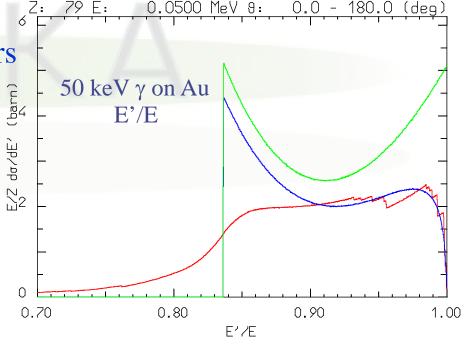
- Activates/deactivates photon Rayleigh scattering.
 Little effect on energy deposition and transport, useful only for specific photon transport problems
- Controls the treatment of Compton scattering.

green = free electron
blue = binding with form factors
red = binding with shells and
orbital motion

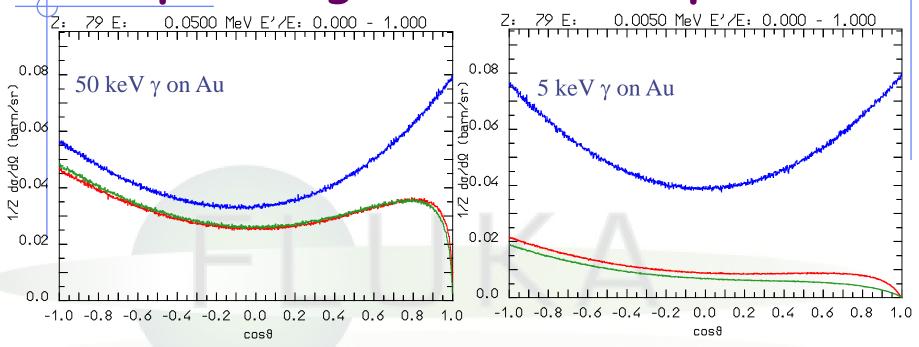
Larger effects at low energy, High-Z materials.

blue curve (old default) ok for most applications

Use the most refined (what(1)=4) for specific low-energy photon transport (default for "precision" defaults....)



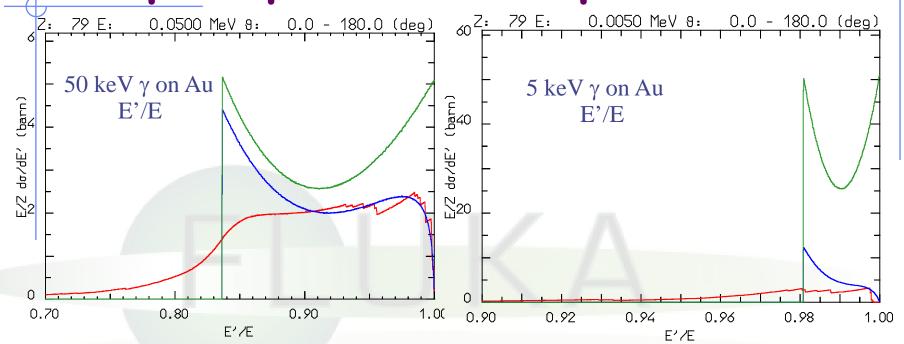
Compton ang. distr.: examples II



blue = free electron green = binding with form factors red = binding with shells and orbital motion

Effects visible only at $cos\theta$ close to 1. The S(q,Z) approximation is still very good at 50 keV,

Compton profile: examples II



green = free electron

blue = binding with form factors

red = binding with shells and orbital motion

Larger effect at very low energies, where, however, the dominant process is photoelectric. Please note that the actual cross section goes down again at low energies!!

Visible: shell structure near E'=E, smearing from motion at low E'₄₅

Other Photon interactions

- Production of muon pairs by photons is off by default. Can be activated through the PHOTONUC card. Biasing of this process is recommended, and is performed with the same PHOTONUC card
- Don't forget that photon and muon photonuclear interactions are off by default
- also e⁺e⁻ electronuclear interactions are off by default and can be activated in the pre-release with PHOTONUC, with SDUM ELECTNUC

Bremsstrahlung and pair production by muons/hadrons

At high energies, bremsstrahlung and pair production are important also for muons and charged hadrons. For instance, in Lead the muon energy loss is dominated by these processes above 300 GeV.

Activation of these processes and thresholds of EXPLICIT γ and exproduction depend on the **DEFAULTs** chosen. They are controlled by the card **PAIRBREM** by material. Three choices are possible for each process:

- > Inhibited: not simulated at all, energy loss NOT taken into account (what(1) < 0)
- Finactive: energy loss is treated as continuous (i.e., without generating secondaries and depositing their energy at the point of production). This reproduces correctly the average ranges but not the straggling and the dose distributions. (what(1) >0, what(2) or what(3) <0)
- Active: the process is fully simulated, with production of secondaries. A threshold for the production can be set, below which energy loss is accounted for in a continuous approximation

HINT: Activate only for high energy problems

Miscellaneous physics settings

Activate photonuclear interactions for all materials

PHOTONUC 1.

1.

@LASTMAT

... maybe with biasing (x 50 in this case)

LAM-BIAS

0.02

PHOTON

Activate $\mu^+ \mu^-$ pair prod. by photons for all materials (biased x10)

PHOTONUC 1.

-0.1

1

@LASTMAT

MUMUPAIR

Activate muon/charged hadrons bremss. (above 100 keV) and e⁺e⁻ pair production for all materials (by default for some DEFAULTS)

PAIRBREM 3.

0.0

0.0001

@LASTMAT

Activate muon photonuclear interactions for all materials

MUPHOTON 1.

1.

@LASTMAT

On top of pairbrem, in order to activate heavy ion direct eterpair production for all materials

PHYSICS 1.

1.

@LASTMAT

IONBRPAI